

#### SMALL SIGNAL COMPLEMENTARY PRE-BIASED DUAL TRANSISTOR

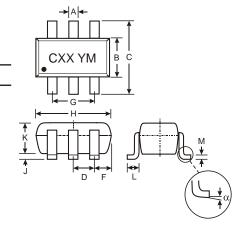
#### **Features**

- Epitaxial Planar Die Construction
- · Built-In Biasing Resistors
- Lead Free/RoHS Compliant (Note 3)
- Surface Mount Package Suited for Automated Assembly

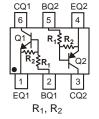
#### **Mechanical Data**

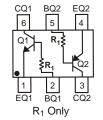
- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Page 4)
- Ordering Information (See Page 4)
- Weight: 0.006 grams (approximate)

P/N	R1	R2	MARKING
DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX143EU DCX144EU	22K 47K 10K 2.2K 10K 4.7K 4.7K 10K	22K 47K 47K 47K 10K - 4.7K	C17 C20 C14 C06 C13 C07 C08



	SOT-363	}				
Dim	Min	Max				
Α	0.10	0.30				
В	1.15	1.35				
С	2.00	2.20				
D	0.65 Nominal					
F	0.30	0.40				
Н	1.80	2.20				
J		0.10				
K	0.90	1.00				
L	0.25	0.40				
М	0.10	0.25				
	0°	8°				
All Dir	nensions	in mm				





Q1: NPN Transistor Q2: PNP Transistor

Diodes Incorporated

SCHEMATIC DIAGRAM

#### Maximum Ratings NPN Section @ TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage, (6) to (1) and (4) to (3)		V <sub>CC</sub>	50	V
Input Voltage, (2) to (1) and (4) to (5)	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX143EU DCX144TU	V <sub>IN</sub>	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5 Vmax -10 to +30 -5 Vmax	V
Output Current	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX143EU DCX143EU DCX114TU	lo	30 30 70 100 50 100 100	mA
Output Current	All	I <sub>C</sub> (Max)	100	mA
Power Dissipation (Total)	(Note 2)	P <sub>d</sub>	200	mW
Thermal Resistance, Junction to Ambient	Air (Note 1)	R <sub>JA</sub>	625	°C/W
Operating and Storage and Temperature	Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

Note: 1. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.

- 2. 150mW per element must not be exceeded.
- No purposefully added lead.



# Maximum Ratings PNP Section @ TA = 25°C unless otherwise specified

Characteris	stic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	Supply Voltage, (3) to (1)		50	V
Input Voltage, (2) to (1)	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX143EU DCX144TU	V <sub>IN</sub>	+10 to -40 +10 to -40 +6 to -40 +5 to -12 +10 to -40 +5 Vmax +10 to -30 +5 Vmax	V
Output Current	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX143EU DCX114TU	Io	-30 -30 -70 -100 -50 -100 -100 -100	mA
Output Current	All	I <sub>C</sub> (Max)	-100	mA
Power Dissipation (Total)	(Page 1: Note 2)	P <sub>d</sub>	200	mW
Thermal Resistance, Junction to Ar	mbient Air (Page 1: Note 1)	R <sub>JA</sub>	625	°C/W
Operating and Storage and Tempe	rature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

### Electrical Characteristics NPN Section @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic (DCX143TU & DCX114TU only)	Symbol	Min	Тур	Max	Unit	Test Condition			
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50			V	I <sub>C</sub> = 50μΑ			
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	50			V	I <sub>C</sub> = 1mA			
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5			V	I <sub>E</sub> = 50μA			
Collector Cutoff Current	I <sub>CBO</sub>			0.5	μΑ	V <sub>CB</sub> = 50V			
Emitter Cutoff Current	I <sub>EBO</sub>			0.5	μΑ	V <sub>EB</sub> = 4V			
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>			0.3	V	I <sub>C</sub> /I <sub>B</sub> = 2.5mA / 0.25mA DCX143TU I <sub>C</sub> /I <sub>B</sub> = 1mA / 0.1mA DCX114TU			
DC Current Transfer Ratio	h <sub>FE</sub>	100	250	600		I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V			
Input Resistor (R <sub>1</sub> ) Tolerance	R <sub>1</sub>	-30		+30	%				
Gain-Bandwidth Product	f⊤		250		MHz	$V_{CE} = 10V, I_{E} = -5mA, f = 100MHz$			



### Electrical Characteristics NPN Section (Continued) @ T<sub>A</sub> = 25°C unless otherwise specified

Characterist	ic	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage  Output Voltage  Input Current	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	$V_{l(off)}$	0.5 0.5 0.3 0.5 0.5	1.1 1.1 1.1 1.16		V	$V_{CC} = 5V$ , $I_{O} = 100 \mu A$
	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V <sub>I(on)</sub>		1.9 1.9 1.9	3.0 3.0 1.4 1.1 3.0 3.0	V	$\begin{array}{c} V_O = 0.3, \ I_O = 5 mA \\ V_O = 0.3, \ I_O = 2 mA \\ V_O = 0.3, \ I_O = 1 mA \\ V_O = 0.3, \ I_O = 5 mA \\ V_O = 0.3, \ I_O = 10 mA \\ V_O = 0.3, \ I_O = 20 mA \\ \end{array}$
Output Voltage	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V <sub>O(on)</sub>		0.1	0.3	V	I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA
Input Current	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	lı			0.36 0.18 0.88 3.6 0.88 0.88	mA	V <sub>I</sub> = 5V
Output Current		$I_{O(off)}$			0.5	μΑ	$V_{CC} = 50V$ , $V_I = 0V$
DC Current Gain	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	G <sub>I</sub>	56 68 68 80 30 50				$V_{O} = 5V$ , $I_{O} = 5mA$ $V_{O} = 5V$ , $I_{O} = 5mA$ $V_{O} = 5V$ , $I_{O} = 10mA$ $V_{O} = 5V$ , $I_{O} = 10mA$ $V_{O} = 5V$ , $I_{O} = 5mA$ $V_{O} = 5V$ , $I_{O} = 10mA$
Input Resistor (R <sub>1</sub> ) Tolerance		R <sub>1</sub>	-30		+30	%	
Resistance Ratio Tolerance		R <sub>2</sub> /R <sub>1</sub>	-20		+20	%	
Gain-Bandwidth Product		f <sub>T</sub>		250		MHz	$V_{CE} = 10V, I_{E} = 5mA,$ f = 100MHz

### Electrical Characteristics PNP Section @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic (DCX143TU & DCX114TU only)	Symbol	Min	Тур	Max	Unit	Test Condition			
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-50			V	I <sub>C</sub> = -50μΑ			
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-50			V	$I_C = -1mA$			
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5			V	I <sub>E</sub> = -50μA			
Collector Cutoff Current	I <sub>CBO</sub>			-0.5	μΑ	V <sub>CB</sub> = -50V			
Emitter Cutoff Current	I <sub>EBO</sub>			-0.5	μΑ	V <sub>EB</sub> = -4V			
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>			-0.3	V	I <sub>C</sub> /I <sub>B</sub> = 2.5mA / 0.25mA DCX143TU I <sub>C</sub> /I <sub>B</sub> = 1mA / 0.1mA DCX114TU			
DC Current Transfer Ratio	h <sub>FE</sub>	100	250	600		$I_C = -1 \text{mA}, V_{CE} = -5 \text{V}$			
Input Resistor (R <sub>1</sub> ) Tolerance	R <sub>1</sub>	-30		+30	%				
Gain-Bandwidth Product	f <sub>T</sub>		250		MHz	$V_{CE} = -10V$ , $I_E = 5mA$ , $f = 100MHz$			



### Electrical Characteristics PNP Section (Continued) @ TA = 25°C unless otherwise specified

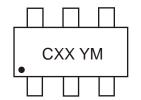
Characterist	ic	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	$V_{I(off)}$	-0.5 -0.5 -0.3 -0.5 -0.5	-1.1 -1.1 -1.1 -1.16		V	$V_{CC} = -5V$ , $I_{O} = -100\mu A$
	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V <sub>I(on)</sub>		-1.9 -1.9 -1.9 -2.5	-3.0 -3.0 -1.4 -1.1 -3.0 -3.0	V	$\begin{array}{l} V_O = \text{-}0.3, \ I_O = \text{-}5\text{mA} \\ V_O = \text{-}0.3, \ I_O = \text{-}2\text{mA} \\ V_O = \text{-}0.3, \ I_O = \text{-}1\text{mA} \\ V_O = \text{-}0.3, \ I_O = \text{-}5\text{mA} \\ V_O = \text{-}0.3, \ I_O = \text{-}10\text{mA} \\ V_O = \text{-}0.3, \ I_O = \text{-}20\text{mA} \\ \end{array}$
Output Voltage	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	V <sub>O(on)</sub>		-0.1	-0.3	V	l <sub>O</sub> /l <sub>I</sub> = -10mA / -0.5mA l <sub>O</sub> /l <sub>I</sub> = -10mA / -0.5mA l <sub>O</sub> /l <sub>I</sub> = -5mA / -0.25mA l <sub>O</sub> /l <sub>I</sub> = -5mA / -0.25mA l <sub>O</sub> /l <sub>I</sub> = -10mA /- 0.5mA l <sub>O</sub> /l <sub>I</sub> = -10mA /- 0.5mA
Input Current	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	lį			-0.36 -0.18 -0.88 -3.6 -0.88 -0.88	mA	V <sub>I</sub> = -5V
Output Current		I <sub>O(off)</sub>			-0.5	μΑ	$V_{CC} = 50V$ , $V_I = 0V$
DC Current Gain	DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143EU	G <sub>I</sub>	56 68 68 80 30 40				$V_O = -5V$ , $I_O = -5mA$ $V_O = -5V$ , $I_O = -5mA$ $V_O = -5V$ , $I_O = -10mA$ $V_O = -5V$ , $I_O = -10mA$ $V_O = -5V$ , $I_O = -5mA$ $V_O = -5V$ , $I_O = -10mA$
Input Resistor (R <sub>1</sub> ) Tolerance	Input Resistor (R <sub>1</sub> ) Tolerance		-30		+30	%	
Resistance Ratio Tolerance		R <sub>2</sub> /R <sub>1</sub>	-20		+20	%	
Gain-Bandwidth Product		f⊤		250		MHz	$V_{CE} = -10V, I_{E} = -5mA,$ f = 100MHz

# Ordering Information (Note 4)

Device	Packaging	Shipping
DCX124EU-7-F	SOT-363	3000/Tape & Reel
DCX144EU-7-F	SOT-363	3000/Tape & Reel
DCX114YU-7-F	SOT-363	3000/Tape & Reel
DCX123JU-7-F	SOT-363	3000/Tape & Reel
DCX114EU-7-F	SOT-363	3000/Tape & Reel
DCX143TU-7-F	SOT-363	3000/Tape & Reel
DCX143EU-7-F	SOT-363	3000/Tape & Reel
DCX114TU-7-F	SOT-363	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



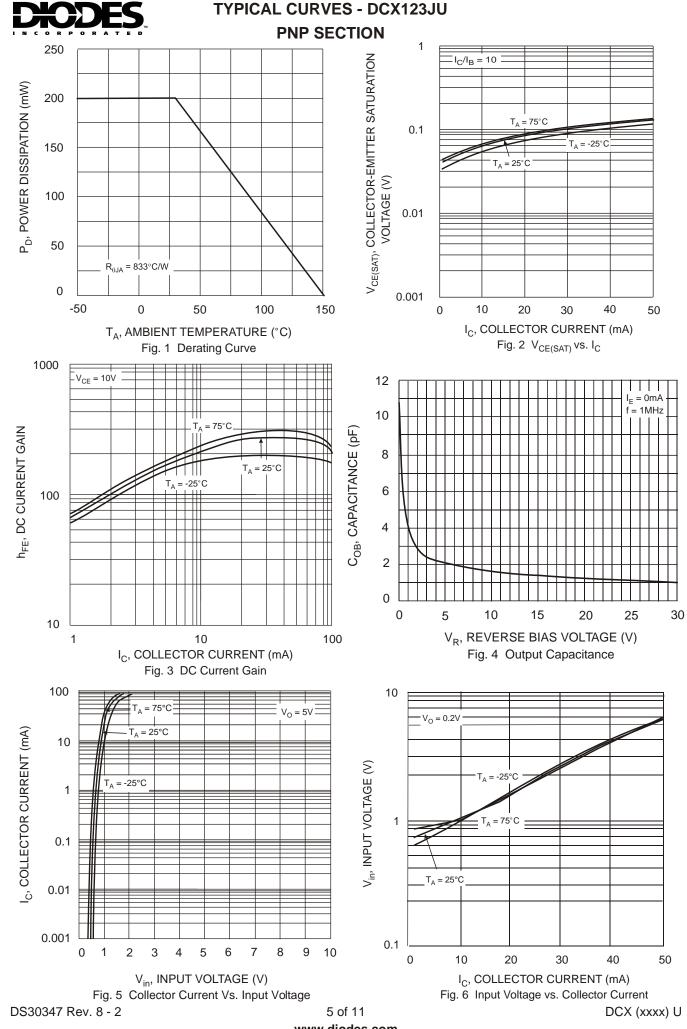
CXX = Product Type Marking Code YM = Date Code Marking

Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

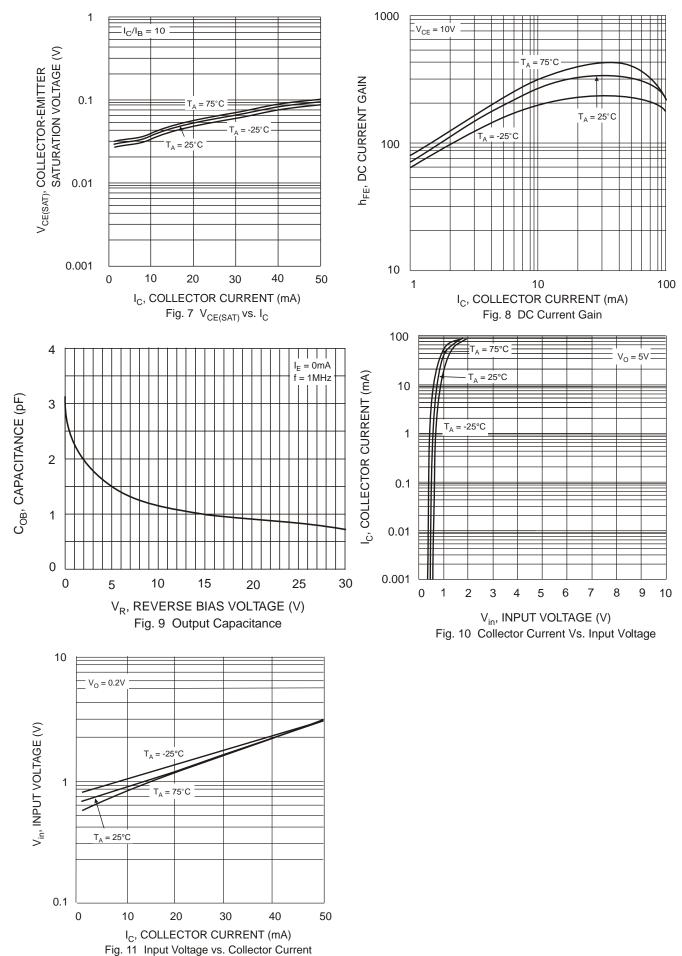
Year	2006	2007	2008	2009	2010	2011	2012
Code	Т	U	V	W	Х	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



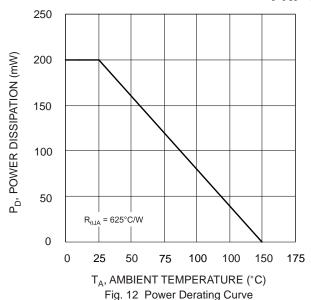


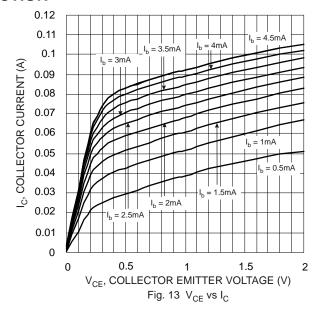
# TYPICAL CURVES - DCX123JU NPN SECTION

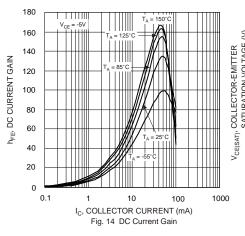


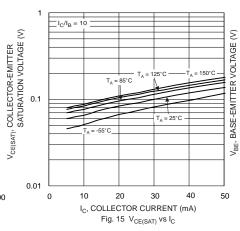


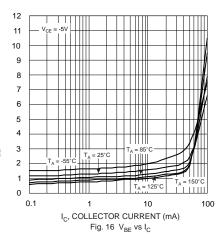
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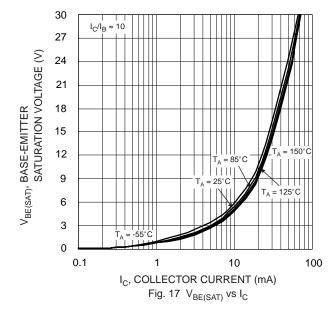


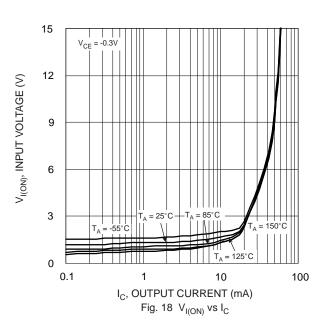






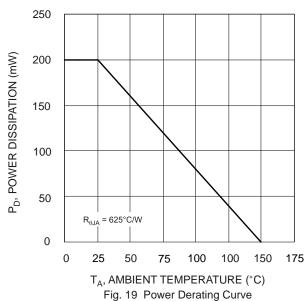


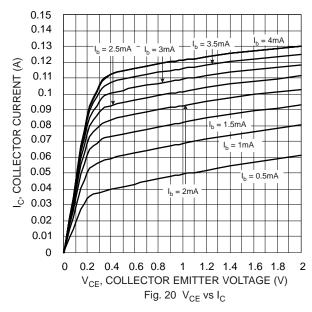


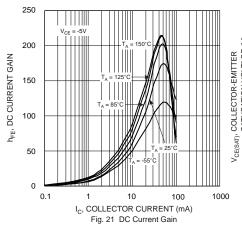


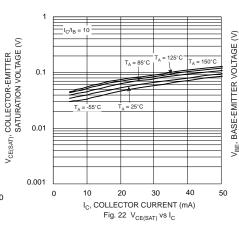


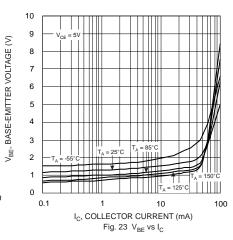
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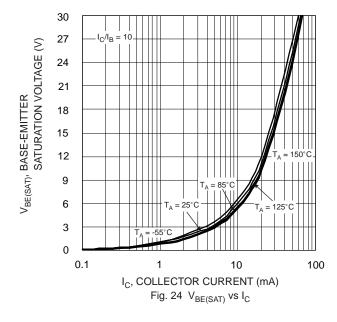


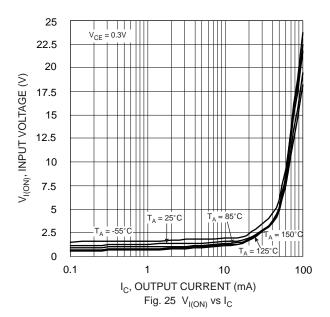












# **TYPICAL CURVES - DCX114TU PNP SECTION**

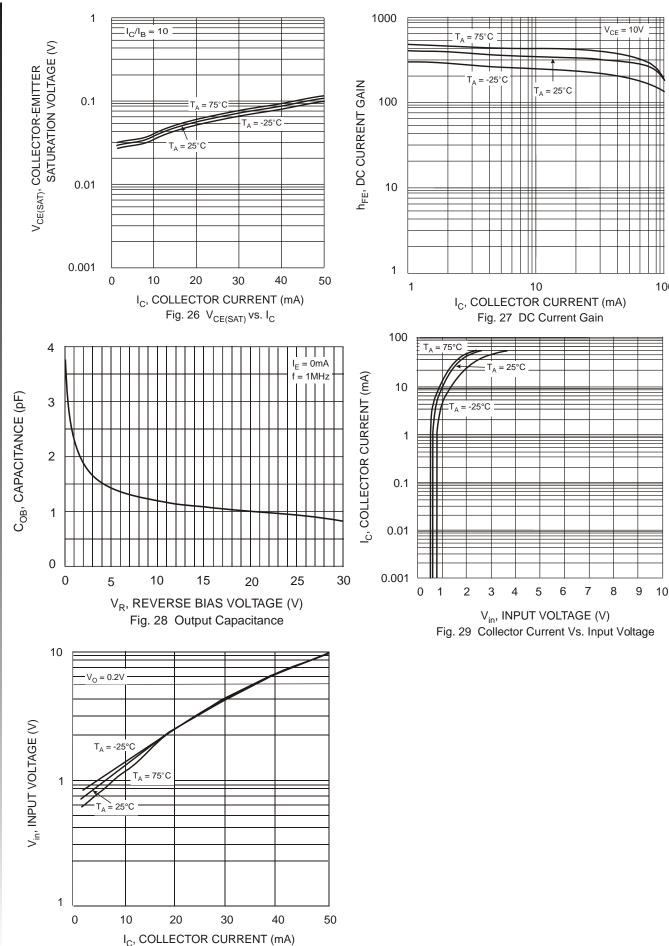
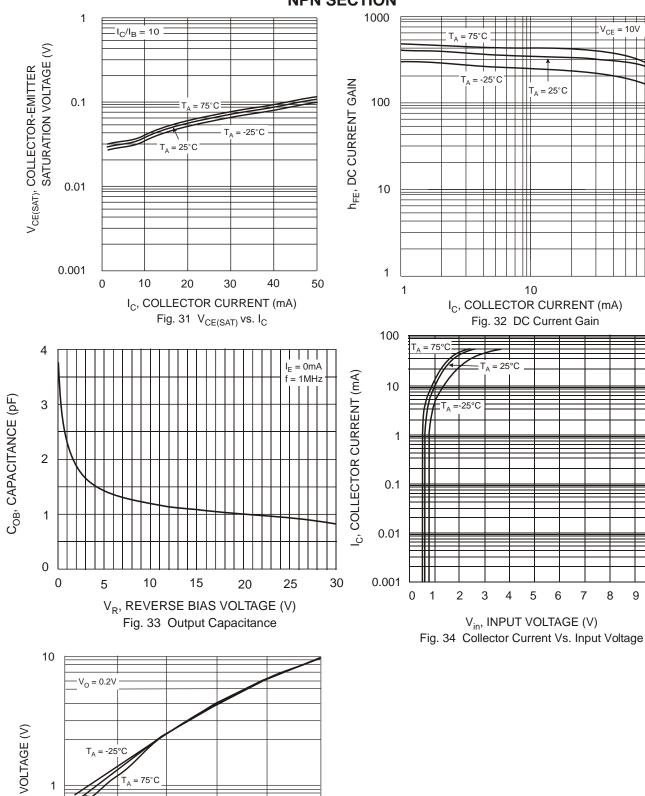


Fig. 30 Input Voltage vs. Collector Current DS30347 Rev. 8 - 2

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# **TYPICAL CURVES - DCX114TU**

#### **NPN SECTION**



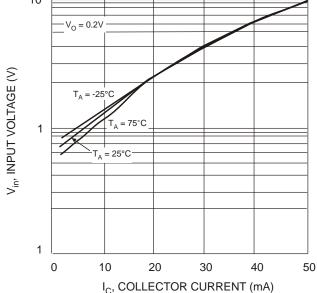


Fig. 35 Input Voltage vs. Collector Current DS30347 Rev. 8 - 2

100

8

9 10



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